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30V, N-Channel NexFET[™] Power MOSFETs

Check for Samples: CSD17301Q5A

FEATURES

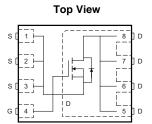
- **Optimized for 5V Gate Drive**
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

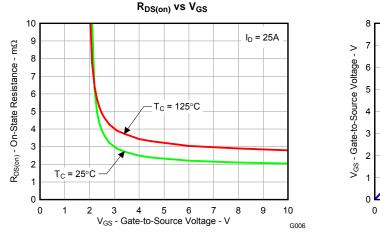
APPLICATIONS

- **Notebook Point of Load**
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems
- **Optimized for Synchronous FET Applications** •

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.





PRODUCT SUMMARY

| V _{DS} | Drain to Source Voltage 30 | | | |
|---------------------|-------------------------------|------------------------|-----|----|
| Qg | Gate Charge Total (4.5V) 19 | | | |
| Q _{gd} | Gate Charge Gate to Drain | 4.3 | nC | |
| | | $V_{GS} = 3V$ | 2.9 | mΩ |
| R _{DS(on)} | Drain to Source On Resistance | $V_{GS} = 4.5V$ | 2.3 | mΩ |
| | | V _{GS} = 8V 2 | | mΩ |
| V _{GS(th)} | Threshold Voltage | 1.1 | V | |

ORDERING INFORMATION

| Device | Package | Media | Qty | Ship |
|-------------|------------------------------------|-----------------|------|------------------|
| CSD17301Q5A | SON 5-mm × 6-mm Plastic Package | 13-inch reel | 2500 | Tape and Reel |

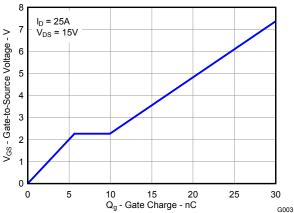
ABSOLUTE MAXIMUM RATINGS

| $T_A = 2$ | 5°C unless otherwise stated | VALUE | UNIT |
|--------------------------------------|----------------------------------------------------------------------------|------------|------|
| V_{DS} | Drain to Source Voltage | 30 | V |
| V_{GS} | Gate to Source Voltage | +10 /8 | V |
| | Continuous Drain Current, $T_C = 25^{\circ}C$ | 100 | А |
| ID | Continuous Drain Current ⁽¹⁾ | 28 | А |
| I _{DM} | Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$ | 181 | А |
| PD | Power Dissipation ⁽¹⁾ | 3.2 | W |
| T _J , T _{STG} | Operating Junction and Storage Temperature Range | -55 to 150 | °C |
| E _{AS} | Avalanche Energy, single pulse I_D = 91A, L = 0.1mH, R_G = 25 Ω | 414 | mJ |

(1) Typical $R_{\theta JA} = 39^{\circ}C/W$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 РСВ.

GATE CHARGE

(2) Pulse duration ≤300µs, duty cycle ≤2%



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XAS **STRUMENTS**

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

| $(T_A = 25^{\circ})$ | °C unless otherwise stated) | | | | | |
|----------------------|----------------------------------|---------------------------------------------------------|-----|------|------|------|
| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| Static Cl | haracteristics | | | | | |
| BV _{DSS} | Drain to Source Voltage | $V_{GS} = 0V, I_D = 250 \mu A$ | 30 | | | V |
| I _{DSS} | Drain to Source Leakage Current | $V_{GS} = 0V, V_{DS} = 24V$ | | | 1 | μA |
| I _{GSS} | Gate to Source Leakage Current | $V_{DS} = 0V, V_{GS} = +10 / -8V$ | | | 100 | nA |
| V _{GS(th)} | Gate to Source Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | 0.9 | 1.1 | 1.55 | V |
| | | $V_{GS} = 3V$, $I_D = 25A$ | | 2.9 | 3.7 | mΩ |
| R _{DS(on)} | Drain to Source On Resistance | $V_{GS} = 4.5V, I_D = 25A$ | | 2.3 | 3 | mΩ |
| | | $V_{GS} = 8V, I_D = 25A$ | | 2 | 2.6 | mΩ |
| 9 _{fs} | Transconductance | V _{DS} = 15V, I _D = 25A | | 149 | | S |
| Dynamic | Characteristics | | | | | |
| C _{iss} | Input Capacitance | | | 2660 | 3480 | pF |
| C _{oss} | Output Capacitance | V _{GS} = 0V, V _{DS} = 15V, f = 1MHz | | 1420 | 1850 | pF |
| C _{rss} | Reverse Transfer Capacitance | | | 80 | 105 | pF |
| R _G | Series Gate Resistance | | | 1.3 | 2.6 | Ω |
| Qg | Gate Charge Total (4.5V) | | | 19 | 25 | nC |
| Q _{gd} | Gate Charge Gate to Drain | | | 4.3 | | nC |
| Q _{gs} | Gate Charge Gate to Source | $V_{DS} = 15V, I_{D} = 25A$ | | 5.7 | | nC |
| Q _{g(th)} | Gate Charge at Vth | | | 2.9 | | nC |
| Q _{oss} | Output Charge | $V_{DS} = 14V, V_{GS} = 0V$ | | 35 | | nC |
| t _{d(on)} | Turn On Delay Time | | | 10.7 | | ns |
| tr | Rise Time | | | 16.2 | | ns |
| t _{d(off)} | Turn Off Delay Time | $V_{DS} = 15V, V_{GS} = 4.5V, I_D = 25A, R_G = 2\Omega$ | | 28 | | ns |
| t _f | Fall Time | | | 10.5 | | ns |
| Diode Cl | haracteristics | · · | | | | |
| V _{SD} | Diode Forward Voltage | I _{SD} = 25A, V _{GS} = 0V | | 0.8 | 1 | V |
| Q _{rr} | Reverse Recovery Charge | | | 50 | | nC |
| t _{rr} | Reverse Recovery Time | V_{DD} = 14V, I _F = 25A, di/dt = 300A/µs | | 33 | | ns |

THERMAL CHARACTERISTICS

| $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ | | | | | | | | |
|-------------------------------------------------------|----------------------------------------------------------|-----|-----|-----|------|--|--|--|
| | PARAMETER | MIN | TYP | MAX | UNIT | | | |
| R_{\thetaJC} | Thermal Resistance Junction to Case ⁽¹⁾ | | | 2.2 | °C/W | | | |
| R_{\thetaJA} | Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾ | | | 49 | °C/W | | | |

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (1)

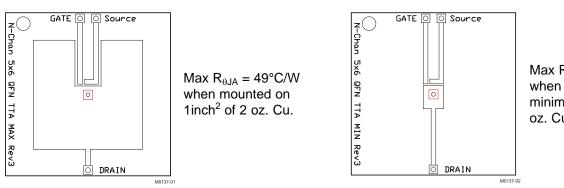
(2)



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Max $R_{\theta JA} = 120^{\circ}C/W$ when mounted on minimum pad area of 2 oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

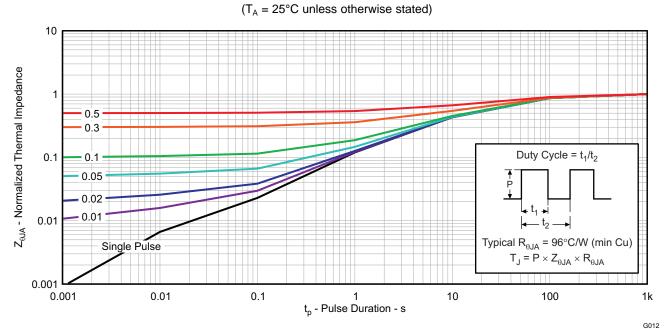


Figure 1. Transient Thermal Impedance

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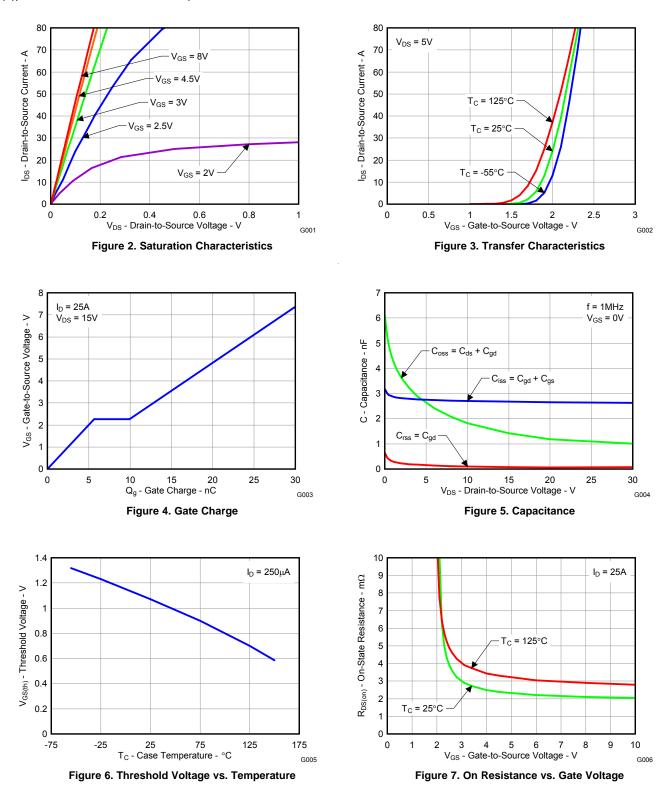
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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



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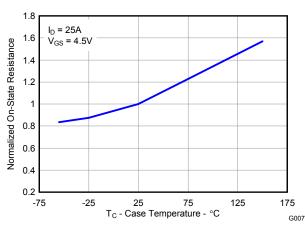


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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





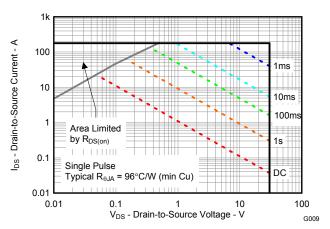


Figure 10. Maximum Safe Operating Area

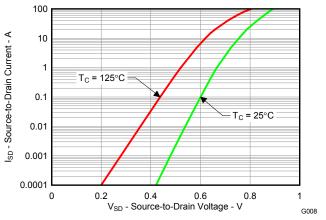


Figure 9. Typical Diode Forward Voltage

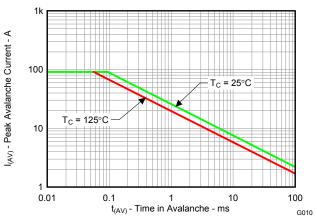
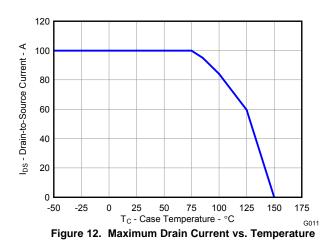


Figure 11. Single Pulse Unclamped Inductive Switching



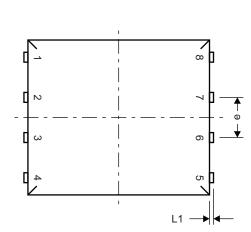
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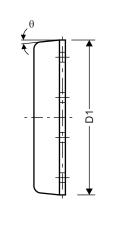
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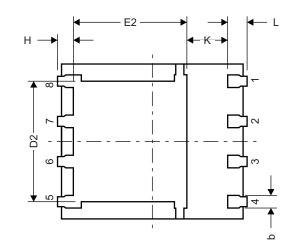
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MECHANICAL DATA

Q5A Package Dimensions



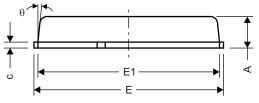




Top View

Side View

Bottom View



Front View

M0135-01

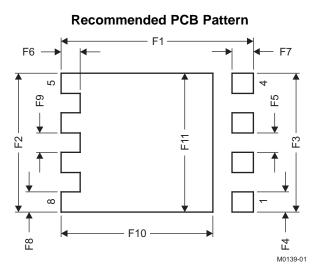
| DIM | | MILLIMETERS | | | | | | |
|-----|------|-------------|------|--|--|--|--|--|
| DIM | MIN | NOM | MAX | | | | | |
| А | 0.90 | 1.00 | 1.10 | | | | | |
| b | 0.33 | 0.41 | 0.51 | | | | | |
| С | 0.20 | 0.25 | 0.34 | | | | | |
| D1 | 4.80 | 4.90 | 5.00 | | | | | |
| D2 | 3.61 | 3.81 | 4.02 | | | | | |
| E | 5.90 | 6.00 | 6.10 | | | | | |
| E1 | 5.70 | 5.75 | 5.80 | | | | | |
| E2 | 3.38 | 3.58 | 3.78 | | | | | |
| е | 1.17 | 1.27 | 1.37 | | | | | |
| Н | 0.41 | 0.56 | 0.71 | | | | | |
| К | 1.10 | | | | | | | |
| L | 0.51 | 0.61 | 0.71 | | | | | |
| L1 | 0.06 | 0.13 | 0.20 | | | | | |
| θ | 0° | | 12° | | | | | |



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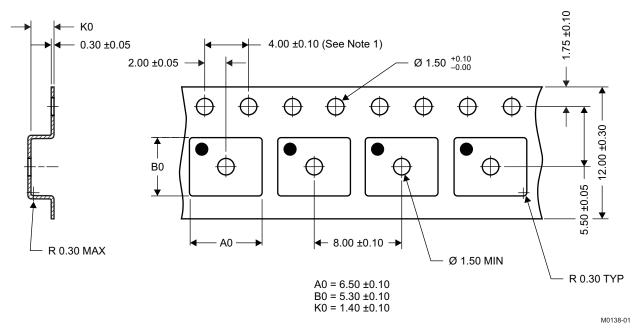
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| DIM | MILLIM | IETERS | INCHES | | | |
|-----|--------|--------|--------|-------|--|--|
| DIM | MIN | MAX | MIN | MAX | | |
| F1 | 6.205 | 6.305 | 0.244 | 0.248 | | |
| F2 | 4.46 | 4.56 | 0.176 | 0.18 | | |
| F3 | 4.46 | 4.56 | 0.176 | 0.18 | | |
| F4 | 0.65 | 0.7 | 0.026 | 0.028 | | |
| F5 | 0.62 | 0.67 | 0.024 | 0.026 | | |
| F6 | 0.63 | 0.68 | 0.025 | 0.027 | | |
| F7 | 0.7 | 0.8 | 0.028 | 0.031 | | |
| F8 | 0.65 | 0.7 | 0.026 | 0.028 | | |
| F9 | 0.62 | 0.67 | 0.024 | 0.026 | | |
| F10 | 4.9 | 5 | 0.193 | 0.197 | | |
| F11 | 4.46 | 4.56 | 0.176 | 0.18 | | |

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

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REVISION HISTORY

Changes from Original (January) to Revision A Page Changed the Abs Max Ratings table, Avalanche Energy, single pulse From: I_D = 85A, L = 0.1mH, R_G = 25 Ω Value = Changed Figure 11 5

Changes from Revision A (February 2010) to Revision B

| • | Updated the Q5A Package Dimensions table. DIM c MAX was 0.30, DIM D2 MAX was 3.96, DIM e MIN was blank MAX was blank, DIM H NOM was 0.51 MAX was 0.61 | 6 |
|----|-------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • | Deleted Note 6 from the Q5A Tape and Reel Information - "MSL1 260°C (IR and convection) PbF reflow compatible" | 7 |
| • | Deleted the Package Marking Information section | 7 |
| Ch | nanges from Revision B (July 2010) to Revision C | Page |

| • | Changed the Abs Max Ratings table, Pulsed Drain Current value From: 118 To: 181 | 1 |
|---|---------------------------------------------------------------------------------|---|

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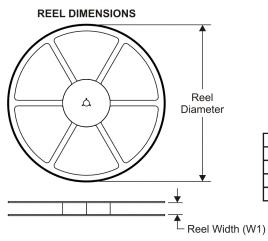
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| CSD17301Q5A | SON | DQJ | 8 | 2500 | 330.2 | 12.4 | 6.5 | 5.3 | 1.4 | 8.0 | 12.0 | Q1 |

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PACKAGE MATERIALS INFORMATION

7-Apr-2011



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CSD17301Q5A | SON | DQJ | 8 | 2500 | 347.0 | 342.0 | 55.0 |

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